

4 Gbit, 8 Gbit, 2112 byte/1056 word page multiplane architecture, 1.8 V or 3 V, NAND Flash memories

Manufacturers	STMicroelectronics, Inc
Package/Case	TSOP48
Product Type	Memory
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for NAND08GW3B2CN6 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

NAND08GW3B2CN6 is a type of NAND Flash memory chip manufactured by Micron Technology. Here are some of its features:

Features

It has a capacity of 8 gigabits (1 gigabyte) and uses a 3-bit per cell (TLC) architecture.

It uses a NAND interface and operates at a voltage range of 2.7V to 3.6V. Solid-state drives (SSDs) used in desktops, laptops, and servers.

It has a maximum program/erase cycle endurance of 3000 cycles and a retention time of up to 3 months at 85°C.

Application

Consumer electronics such as smartphones, tablets, and portable media players.

Automotive applications such as infotainment systems and advanced driver-assistance systems (ADAS).





Related Products



[NAND01GW3B2BN6E](#)

STMicroelectronics, Inc
TSOP-48



[NAND512W3A2BN6E](#)

STMicroelectronics, Inc
TSOP-1-48



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[M29W640GB-70NA6](#)

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[NAND512W3A2BZA6](#)

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TSOP-48